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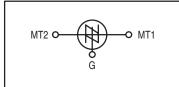
Silicon Bidirectional SwitchesDiode Thyristors

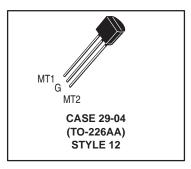
... designed for full-wave triggering in Triac phase control circuits, half-wave SCR triggering application and as voltage level detectors. Supplied in an inexpensive plastic TO-226AA package for high-volume requirements, this low-cost plastic package is readily adaptable for use in automatic insertion equipment.

- Low Switching Voltage 8 Volts Typical
- Uniform Characteristics in Each Direction
- Low On-State Voltage 1.7 Volts Maximum
- Low Off-State Current 0.1 μA Maximum
- Low Temperature Coefficient 0.02 %/°C Typical

MBS4991 MBS4992 MBS4993

> SBS (PLASTIC)





MAXIMUM RATINGS (T_J = 25°C unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Dissipation	PD	500	mW
DC Forward Current	lF	200	mA
DC Gate Current (Off-State Only)	IG(off)	5	mA
Repetitive Peak Forward Current (1% Duty Cycle, 10 μs Pulse Width, T _A = 100°C)	I _{FM} (rep)	2	Amps
Non-repetitive Forward Current (10 μs Pulse Width, T _A = 25°C)	I _{FM} (nonrep)	6	Amps
Operating Junction Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

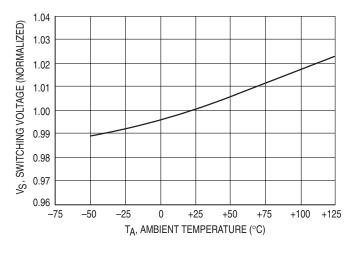
MBS4991 MBS4992 MBS4993

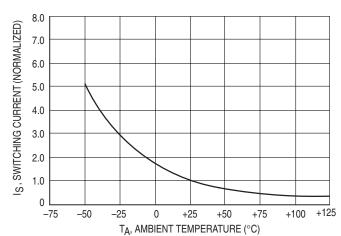
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted.)

Characteristic		Symbol	Min	Тур	Max	Unit
Switching Voltage	MBS4991 MBS4992, MBS4993	٧s	6 7.5	8 8	10 9	Vdc
Switching Current	MBS4991 MBS4992 MBS4993	IS	_	175 90 175	500 120 250	μAdc
Switching Voltage Differential (See Figure 10)	MBS4991 MBS4992, MBS4993	V _{S1} -V _{S2}	_	0.3 0.1	0.5 0.2	Vdc
Gate Trigger Current (V _F = 5 Vdc, R _L = 1 k ohm)	MBS4992 MBS4993	lGF	_	_	100 500	μAdc
Holding Current	MBS4991 MBS4992 MBS4993	lн	_ _ _	0.7 0.2 0.3	1.5 0.5 0.75	mAdc
Off-State Blocking Current $(V_F = 5 \text{ Vdc}, T_A = 25^{\circ}\text{C})$ $(V_F = 5 \text{ Vdc}, T_A = 85^{\circ}\text{C})$ $(V_F = 5 \text{ Vdc}, T_A = 25^{\circ}\text{C})$ $(V_F = 5 \text{ Vdc}, T_A = 100^{\circ}\text{C})$	MBS4991 MBS4991 MBS4992, MBS4993 MBS4992, MBS4993	Ι _Β	 - - -	0.08 2 0.08 6	1 10 0.1 10	μAdc
Forward On-State Voltage (I _F = 175 mAdc) (I _F = 200 mAdc)	MBS4991 MBS4992, MBS4993	VF	=	1.4 1.5	1.7 1.7	Vdc
Peak Output Voltage (C _C = 0.1 μF, R _L = 20 ohms, (Figure 7)		Vo	3.5	4.8	_	Vdc
Turn-On Time (Figure 8)		t _{on}	-	1	_	μs
Turn-Off Time (Figure 9)		^t off	-	30	_	μs
Temperature Coefficient of Switching Voltage (-50 to +125°C)		TC	-	+0.02	_	%/°C
Switching Current Differential (See Figure 10)		I _{S1} -I _{S2}	T —	_	100	μΑ

TYPICAL ELECTRICAL CHARACTERISTICS

FIGURE 1 – SWITCHING VOLTAGE versus TEMPERATURE FIGURE 2 – SWITCHING CURRENT versus TEMPERATURE





MBS4991 MBS4992 MBS4993

FIGURE 3 - HOLDING CURRENT versus TEMPERATURE

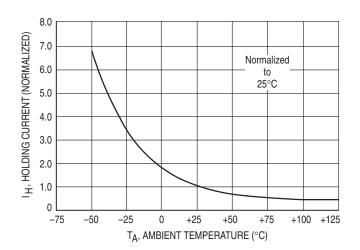


FIGURE 4 – OFF-STATE BLOCKING CURRENT versus TEMPERATURE

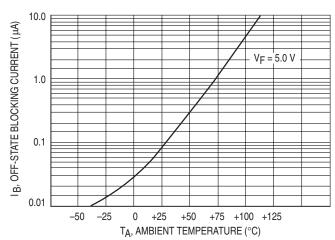
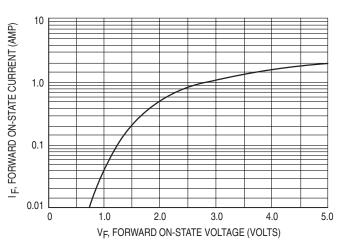


FIGURE 5 - ON-STATE VOLTAGE versus FORWARD CURRENT FIGURE 6 - PEAK OUTPUT VOLTAGE (FUNCTION OF RL AND Cc)



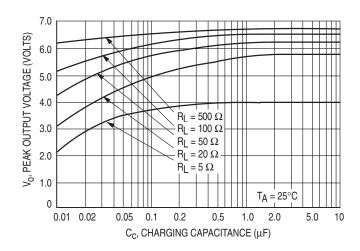


FIGURE 7 - PEAK OUTPUT VOLTAGE TEST CIRCUIT

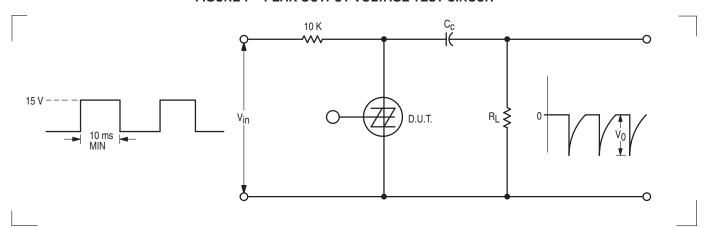
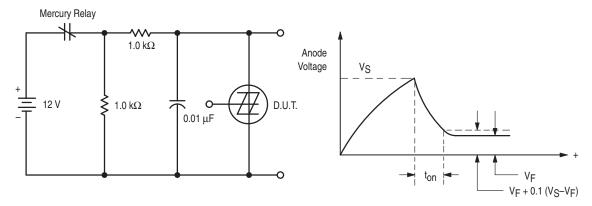
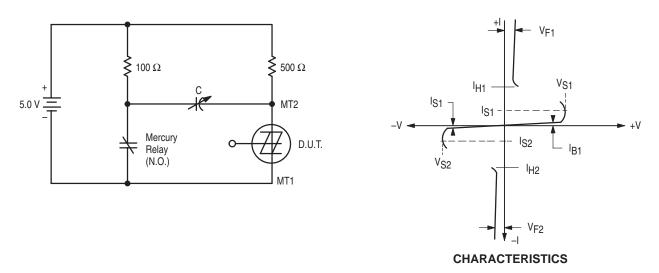


FIGURE 8 – TURN-ON TIME TEST CIRCUIT



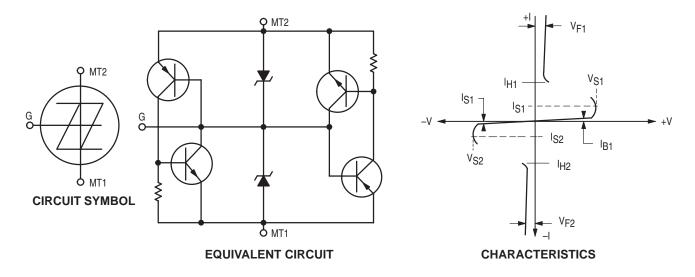
Turn-on time is measured from the time V_S is achieved to the time when the anode voltage drops to within 90% of the difference between V_S and V_F .

FIGURE 9 - TURN-OFF TIME TEST CIRCUIT

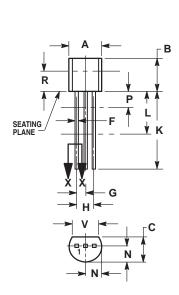


With the SBS in conduction and the relay contacts open, close the contacts to cause anode A2 to be driven negative. Decrease C until the SBS just remains off when anode A2 becomes positive. The turn off time, t_{Off}, is the time from initial contact closure and until anode A2 voltage reaches zero volts.

FIGURE 10 - DEVICE EQUIVALENT CIRCUIT, CHARACTERISTICS AND SYMBOLS



PACKAGE DIMENSIONS



STYLE 12:
PIN 1. MAIN TERMINAL 1
2. GATE
3. MAIN TERMINAL 2



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		

CASE 29-04 (TO-226AA)

MBS4991 MBS4992 MBS4993

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